MOSEL VITELIC V62C518256 32K X 8 STATIC RAM

PRELIMINARY

Features

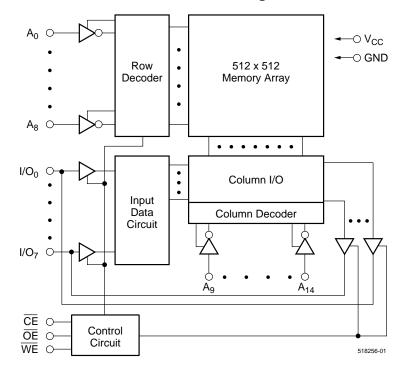
- High-speed: 35, 70 ns
- Ultra low DC operating current of 5mA (max.)
- Low Power Dissipation:
 - TTL Standby: 3 mA (Max.)
 - CMOS Standby: 20 μA (Max.)
- Fully static operation
- All inputs and outputs directly compatible
- Three state outputs
- Ultra low data retention current ($V_{CC} = 2V$)
- Single 5V ± 10% Power Supply

Packages

- 28-pin TSOP (Standard)
- 28-pin 600 mil PDIP
- 28-pin 330 mil SOP (450 mil pin-to-pin)

Description

The V62C518256 is a 262,144-bit static random access memory organized as 32,768 words by 8 bits. It is built with MOSEL VITELIC's high performance CMOS process. Inputs and three-state outputs are TTL compatible and allow for direct interfacing with common system bus structures.



Functional Block Diagram

Device Usage Chart

Operating	Package Outline		ne	Access Time (ns)		Power		Tomorotomo	
Temperature Range	т	Р	F	35	70	L	LL	Temperature Mark	
0°C to 70 °C	•	•	•	•	•	•	•	Blank	
–40°C to +85°C	•	•	•	•	•	•	•	I	

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Pin Descriptions

A₀–A₁₄ Address Inputs

These 15 address inputs select one of the 32,768 x 8 bit segments in the RAM.

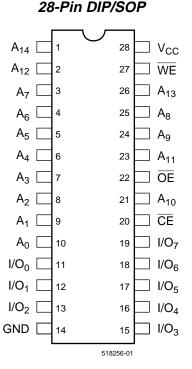
CE Chip Enable Inputs

 \overline{CE} is an active LOW input. Chip Enable must be LOW when reading from or writing to the device. When HIGH, the device is in standby mode with I/O pins in the high impedance state.

OE Output Enable Input

The Output Enable input is active LOW. When \overline{OE} is LOW with \overline{CE} LOW and \overline{WE} HIGH, data of the selected memory location will be available on the I/O pins. When \overline{OE} is HIGH, the I/O pins will be in the high impedance state.

Pin Configurations (Top View)



WE Write Enable Input

An active LOW input, $\overline{\text{WE}}$ input controls read and write operations. When $\overline{\text{CE}}$ and $\overline{\text{WE}}$ inputs are both LOW, the data present on the I/O pins will be written into the selected memory location.

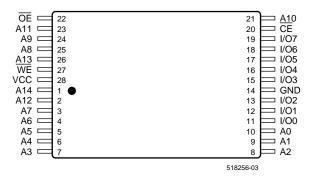
I/O₀–I/O₇ Data Input and Data Output Ports

These 8 bidirectional ports are used to read data from and write data into the RAM.

V_{CC} Power Supply

GND Ground

28-Pin TSOP (Standard)



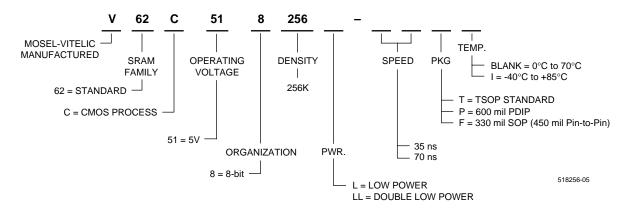
the 32,768 x write

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Part Number Information



Absolute Maximum Ratings (1)

Symbol	Parameter	Commercial	Industrial	Units
V _{CC}	Supply Voltage	-0.5 to +7	-0.5 to +7	V
V _N	Input Voltage	-0.5 to +7	-0.5 to +7	V
V _{DQ}	Input/Output Voltage Applied	V _{CC} + 0.5	V _{CC} + 0.5	V
T _{BIAS}	Temperature Under Bias	-10 to +125	-65 to +135	°C
T _{STG}	Storage Temperature	-65 to +150	-65 to +150	°C

NOTE:

1. Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Capacitance*

 $T_A = 25^{\circ}C$, f = 1.0MHz

Symbol	Parameter	Conditions	Max.	Unit
C _{IN}	Input Capacitance	$V_{IN} = 0V$	6	pF
C _{OUT}	Output Capacitance	$V_{I/O} = 0V$	8	pF

NOTE:

* This parameter is guaranteed and not tested.

Truth Table

Mode	CE	ŌĒ	WE	I/O Operation
Standby	Н	Х	Х	High Z
Read	L	L	Н	D _{OUT}
Read	L	Н	Н	High Z
Write	L	Х	L	D _{IN}

NOTE:

X = Don't Care, L = LOW, H = HIGH

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Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Units
V _{IL}	Input LOW Voltage ^(1,2)		-0.5	_	0.8	V
VIH	Input HIGH Voltage ⁽¹⁾		2.2	_	6	V
I _{IL}	Input Leakage Current	$V_{CC} = Max, V_{IN} = 0V \text{ to } V_{CC}$	-2	_	2	μΑ
I _{OL}	Output Leakage Current	$V_{CC} = Max, \overline{CE} = V_{IH}, V_{OUT} = 0V \text{ to } V_{CC}$	-2	_	2	μA
V _{OL}	Output LOW Voltage	$V_{CC} = Min, I_{OL} = 2.1mA$	_	_	0.4	V
V _{OH}	Output HIGH Voltage	V _{CC} = Min, I _{OH} = -1mA	2.4	_		V

DC Electrical Characteristics (over all temperature ranges, $V_{CC} = 5V \pm 10\%$)

Symbol	Parameter		Power	Com. ⁽⁴⁾	Ind. ⁽⁴⁾	Units
I _{CC}	Operating Power Supply Current, $\overline{CE} = V_{IL}$	READ		5	6	mA
	Output Open, V _{CC} = Max., f = 0	WRITE		40	50	
I _{CC1}	Average Operating Current, $\overline{CE} \le V_{IL}$ Output Open, $V_{CC} = Max., f = f_{MAX}^{(3)}$			60	70	mA
I _{SB}	TTL Standby Current		L	4	5	mA
	$\overline{CE} \ge V_{IH}, V_{CC} = Max.$		LL	3	4	
I_{SB1} CMOS Standby Current, $\overline{CE} \ge V_{CC} - 0.2V$,			L	60	70	μA
	$V_{IN} \ge V_{CC} - 0.2V \text{ or } V_{IN} \le 0.2V, V_{CC} = Max.$		LL	20	30	

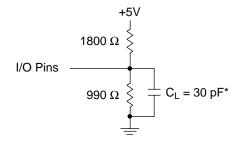
NOTES:

- 1. These are absolute values with respect to device ground and all overshoots due to system or tester noise are included.
- 2. V_{IL} (Min.) = -3.0V for pulse width < 20ns.
- 3. $f_{MAX} = 1/t_{RC}$.
- 4. Maximum values.

AC Test Conditions

Input Pulse Levels	0 to 3V
Input Rise and Fall Times	5 ns
Timing Reference Levels	1.5V
Output Load	see below

AC Test Loads and Waveforms



* Includes scope and jig capacitance

518256-06

Key to Switching Waveforms

WAVEFORM	INPUTS	OUTPUTS
	MUST BE STEADY	WILL BE STEADY
	MAY CHANGE FROM H TO L	WILL BE CHANGING FROM H TO L
	MAY CHANGE FROM L TO H	WILL BE CHANGING FROM L TO H
	DON'T CARE: ANY CHANGE PERMITTED	CHANGING: STATE UNKNOWN
$\mathbb{P}\mathbb{C}$	DOES NOT APPLY	CENTER LINE IS HIGH IMPEDANCE "OFF" STATE

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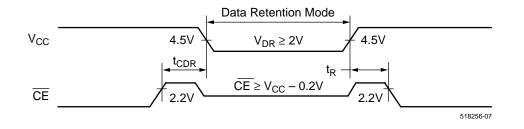
Data Retention Characteristics

Symbol	Parameter		Power	Min.	Typ. ⁽²⁾	Max.	Units
V _{DR}	V_{CC} for Data Retention $\overline{CE} \ge V_{CC} - 0.2V$			2.0	—	5.5	V
I _{CCDR}	I_{CCDR} Data Retention Current $V_{DR} = 3.0V, \ \overline{CE} \ge V_{DR} - 0.2V$	Com'l	L	_	0.5	50	μΑ
			LL	_	0.5	15]
		Ind.	L	_	—	70]
			LL	_	_	20	
t _{CDR}	Chip Deselect to Data Retention Time	*		0	—	_	ns
t _R	Operation Recovery Time (see Retention Wavefor	m)		t _{RC} ⁽¹⁾	_		ns

NOTES:

1. t_{RC} = Read Cycle Time 2. T_A = +25°C.

Low V_{CC} Data Retention Waveform



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AC Electrical Characteristics

(over all temperature ranges)

Read Cycle

Parameter		-35		-70		
Name	Parameter	Min.	Max.	Min.	Max.	Unit
t _{RC}	Read Cycle Time	35	_	70	_	ns
t _{AA}	Address Access Time	_	35	_	70	ns
t _{ACS}	Chip Enable Access Time	_	35	—	70	ns
^t OE	Output Enable to Output Valid	_	15	_	30	ns
^t CLZ	Chip Enable to Output in Low Z	5	_	5	_	ns
t _{OLZ}	Output Enable to Output in Low Z	5	_	5	_	ns
t _{CHZ}	Chip Disable to Output in High Z	0	20	0	20	ns
t _{OHZ}	Output Disable to Output in High Z	0	20	0	20	ns
t _{ОН}	Output Hold from Address Change	5	_	5	_	ns

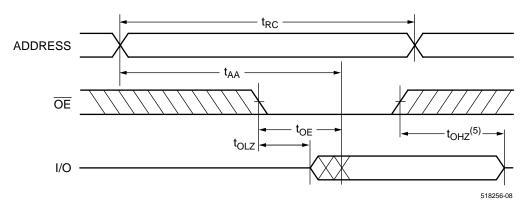
Write Cycle

Parameter		-35		-70		
Name	Parameter	Min.	Max.	Min.	Max.	Unit
^t WC	Write Cycle Time	35	—	70	—	ns
t _{CW}	Chip Enable to End of Write	35	—	60	—	ns
t _{AS}	Address Setup Time	0	_	0	—	ns
t _{AW}	Address Valid to End of Write	35	_	60	—	ns
t _{WP}	Write Pulse Width	25	—	50	—	ns
t _{WR}	Write Recovery Time	0	_	0	_	ns
t _{WHZ}	Write to Output High-Z	0	20	0	25	ns
t _{DW}	Data Setup to End of Write	25	—	30	—	ns
t _{DH}	Data Hold from End of Write	0	_	0	_	ns
^t OHZ	Output Disable to Output in High Z	0	25	0	30	ns
t _{OW}	Output Active from End of Write	5	—	5	—	ns

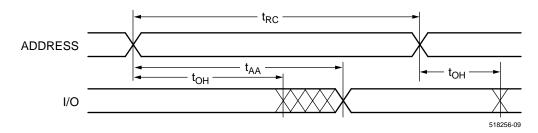
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Switching Waveforms (Read Cycle)

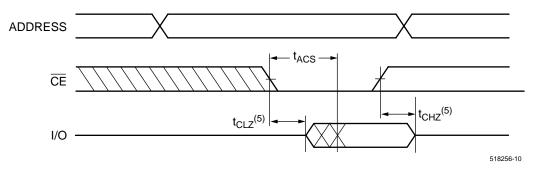
Read Cycle 1^(1, 2)



Read Cycle 2^(1, 2, 4)







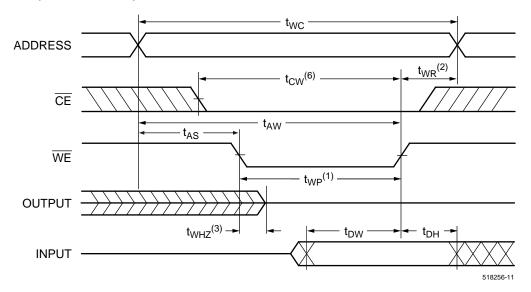
NOTES:

- 1. $\overline{WE} = V_{IH}$.
- 2. $\overline{CE} = V_{IL}$.
- 3. Address valid prior to or coincident with \overline{CE} transition LOW.
- 4. $\overline{OE} = V_{IL}$.
- 5. Transition is measured \pm 500mV from steady state with C_L = 5pF. This parameter is guaranteed and not 100% tested.

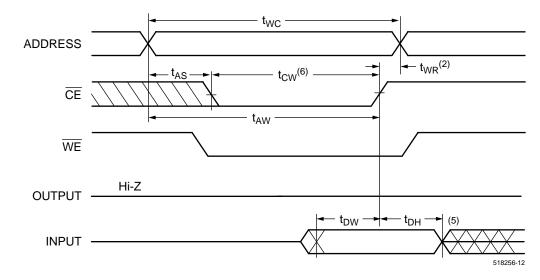
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Switching Waveforms (Write Cycle)

Write Cycle 1 (WE Controlled)⁽⁴⁾



Write Cycle 2 (CE Controlled)⁽⁴⁾



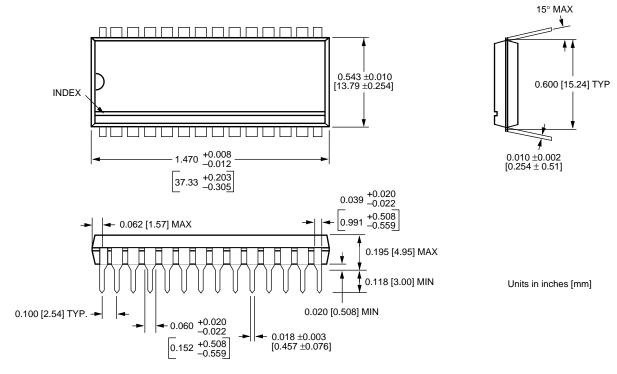
NOTES:

- The internal write time of the memory is defined by the overlap of CE active and WE low. Both signals must be active to initiate and any one signal can terminate a write by going inactive. The data input setup and hold timing should be referenced to the second transition edge of the signal that terminates the write.
- 2. t_{WR} is measured from the earlier of \overline{CE} or \overline{WE} going HIGH.
- 3. During this period, I/O pins are in the output state so that the input signals of opposite phase to the outputs must not be applied.
- 4. $\overline{OE} = V_{IL}$ or V_{IH} . However it is recommended to keep \overline{OE} at V_{IH} during write cycle to avoid bus contention.
- 5. If CE is LOW during this period, I/O pins are in the output state. Then the data input signals of opposite phase to the outputs must not be applied to them.
- 6. t_{CW} is measured from \overline{CE} going LOW to the end of write.

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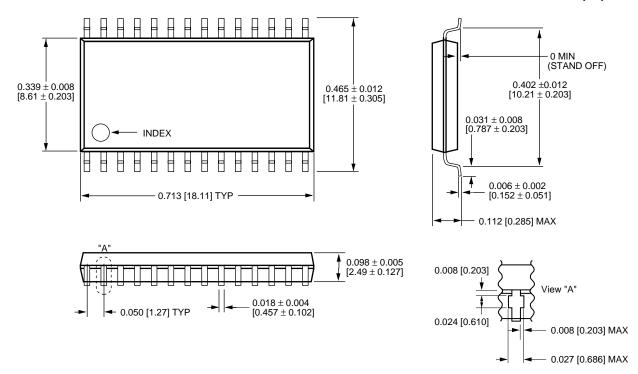
Package Diagrams

28-pin 600 mil Plastic DIP



28-pin 330 mil SOP

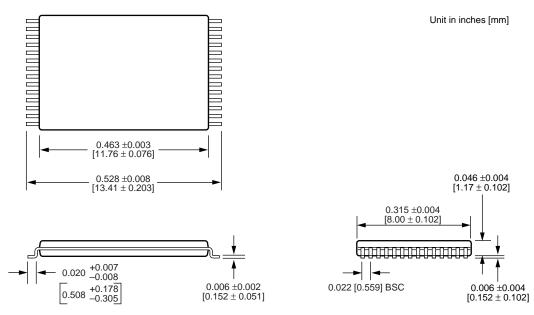
Units in inches [mm]



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Package Diagrams (Cont'd)

28-Pin TSOP



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11/98 Printed in U.S.A.

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